

# Low Power FM Transmitter System

MC2833 is a one-chip FM transmitter subsystem designed for cordless telephone and FM communication equipment. It includes a microphone amplifier, voltage controlled oscillator and two auxiliary transistors.

- Wide Range of Operating Supply Voltage (2.8-9.0 V)
- Low Drain Current (ICC = 2.9 mA Typ)
- Low Number of External Parts Required
- 30 dBm Power Output to 60 MHz Using Direct RF Output
- +10 dBm Power Output Attainable Using On-Chip Transistor Amplifiers
- Users Must Comply with Local Regulations on R.F. Transmission (FCC, DOT, P.T.T., etc)

## **Representative Block Diagram** 1 $\bigcirc$ RF Osc Variable **−**○ 15 2 () Reactance 3 🔿 Buffer Mic Amp → 13 $\bigcirc$ 12 5 🔿 → 11 **VREF →** 10 7 🔿 8 () **→** 9

### MC2833

# LOW POWER FM TRANSMITTER SYSTEM

SEMICONDUCTOR TECHNICAL DATA





P SUFFIX PLASTIC PACKAGE CASE 648 D SUFFIX
PLASTIC PACKAGE
CASE 751B
(SO-16)

#### **PIN CONNECTIONS** Variable Reactance Output Osc 15 Decoupling Modulator 14 Output Input Mic Amp 13 Base Output Tr 2 Emitter Mic Amp Input Tr 2 Gnd 6 11 Collector Tr 1 10 V<sub>CC</sub> Emitter Tr 1 Tr 1 9 Collector Base

#### **ORDERING INFORMATION**

Device	Operating Temperature Range	Package
MC2833D	T 20 to .7500	SO-16
MC2833P	$T_A = -30 \text{ to } +75^{\circ}\text{C}$	Plastic DIP

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#### MC2833

#### **MAXIMUM RATINGS**

Ratings	Symbol	Value	Unit
Power Supply Voltage	VCC	10 (max)	V
Operating Supply Voltage Range	VCC	2.8–9.0	V
Junction Temperature	TJ	+ 150	°C
Operating Ambient Temperature	TA	- 30 to + 75	°C
Storage Temperature Range	T <sub>stg</sub>	- 65 to + 150	°C

#### **ELECTRICAL CHARACTERISTICS** ( $V_{CC}$ = 4.0 V, $T_{A}$ = 25°C, unless otherwise noted)

Characteristics	Symbol	Pin	Min	Тур	Max	Unit
Drain Current (No input signal)	Icc	10	1.7	2.9	4.3	mA
FM MODULATOR			•	•		
Output RF Voltage (f <sub>O</sub> = 16.6 MHz)	V <sub>out</sub> RF	14	60	90	130	mVrms
Output DC Voltage (No input signal)	Vdc	14	2.2	2.5	2.8	V
Modulation Sensitivity (f <sub>0</sub> = 16.6 MHz) (V <sub>in</sub> = 0.8 V to 1.2 V)	SEN	3 14	7.0 -	10 -	15 -	Hz/mVdc
Maximum Deviation (f <sub>O</sub> = 16.6 MHz) (V <sub>in</sub> = 0 V to 2.0 V)	Fdev	3 14	3.0	5.0 -	10 -	kHz
MIC AMPLIFIER						
Closed Loop Voltage Gain (V <sub>in</sub> = 3.0 mVrms) (f <sub>in</sub> = 1.0 kHz)	A <sub>V</sub>	4 5	27 -	30 -	33 -	dB
Output DC Voltage (No input signal)	V <sub>out</sub> dc	4	1.1	1.4	1.7	V
Output Swing Voltage (V <sub>in</sub> = 30 mVrms) (f <sub>in</sub> = 1.0 kHz)	Vout P-P	4	0.8	1.2	1.6	Vp–p
Total Harmonic Distortion (V <sub>in</sub> = 3.0 mVrms) (f <sub>in</sub> = 1.0 kHz)	THD	4	_	0.15	2.0	%

#### **AUXILIARY TRANSISTOR STATIC CHARACTERISTICS**

Characteristics	Symbol	Min	Тур	Max	Unit
Collector Base Breakdown Voltage (I <sub>C</sub> = 5.0 μA)	V <sub>(BR)</sub> CBO	15	45	_	V
Collector Emitter Breakdown Voltage (I <sub>C</sub> = 200 μA)	V <sub>(BR)</sub> CEO	10	15	_	V
Collector Substrate Breakdown Voltage (I <sub>C</sub> = 50 μA)	V <sub>(BR)</sub> CSO	_	70	_	V
Emitter Base Breakdown Voltage (I <sub>E</sub> = 50 μA)	V <sub>(BR)EBO</sub>	_	6.2	_	V
Collector Base Cut Off Current (V <sub>CB</sub> = 10 V) (I <sub>E</sub> = 0)	I <sub>CBO</sub>	_	_	200	nA
DC Current Gain (I <sub>C</sub> = 3.0 mA) (V <sub>CE</sub> = 3.0 V)	hFE	40	150	-	-

#### **AUXILIARY TRANSISTOR DYNAMIC CHARACTERISTICS**

Current Gain Bandwidth Product (V <sub>CE</sub> = 3.0 V) (I <sub>C</sub> = 3.0 mA)	fT	-	500	-	MHz
Collector Base Capacitance ( $V_{CE} = 3.0 \text{ V}$ ) ( $I_{C} = 0$ )	ССВ	-	2.0	-	pF
Collector Substrate Capacitance ( $V_{CS} = 3.0 \text{ V}$ ) ( $I_{C} = 0$ )	C <sub>CS</sub>	ı	3.3	ı	pF

Figure 1. Test Circuit

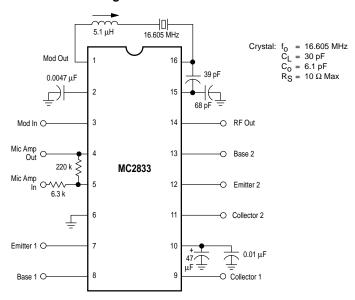
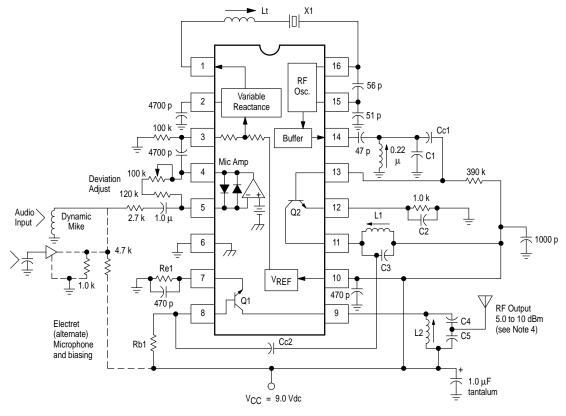


Figure 2. Single Chip VHF Narrowband FM Transmitter



#### NOTES:

1. Components versus output frequency:

Output RF	X1 (MHz)	<u>Lt (μH)</u>	<u>L1 (μH)</u>	<b>L2 (μH)</b>	Re1	Rb1	Cc1	Cc2	<u>C1</u>	C2	C3	C4	C5
50 MHz	16.6667	3.3-4.7	0.22	0.22	330	390 k	33 p	33 p	33 p	470 p	33 p	47 p	220 p
76 MHz	12.6000	5.1	0.22	0.22	150	300 k	68 p	10 p	68 p	470 p	12 p	20 p	120 p
144 MHz	12	5.6	0.15	0.10	150	220 k	47 p	10 p	68 p	1000 p	18 p	12 p	33 p

- Crystal X1 is fundamental mode, calibrated for parallel resonance with a 32 pF load. The final output frequency is generated by frequency multiplication within the MC2833 IC. The RF output buffer (Pin 14) and Q2 transistor are used as a frequency tripler and doubler, respectively, in the 76 and 144 MHz transmitters. The Q1 output transistor is a linear amplifier in the 49.7 MHz and 76 MHz transmitters, and a frequency doubler in the 144 MHz transmitter.
   All coils used are 7 mm shielded inductors, CoilCraft series M1175A, M1282A–M1289A, M1312A or equivalent.
   Power output is ≈ + 10 dBm for 50 MHz and 76 MHz transmitters, and ≈ + 5.0 dBm for the 144 MHz transmitter at V<sub>CC</sub> = 8.0 V. Power output drops with lower

- $\label{eq:VCC} \mbox{VCC.} \\ \mbox{All capacitors in microfarads, inductors in Henries and resistors in Ohms unless otherwise specified.}$
- Other frequency combinations may be set-up by simple scaling of the 3 examples shown.

Figure 3. Buffer/Multiplier (x3, Pin 14) (16 MHz Fundamental)

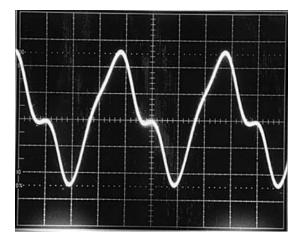


Figure 5. Doubler Output 76 MHz (Pin 11)

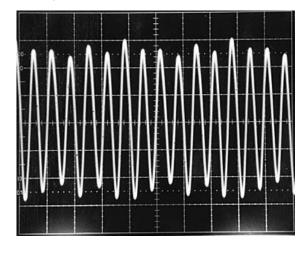


Figure 7. Output Spectrum (50 MHz)

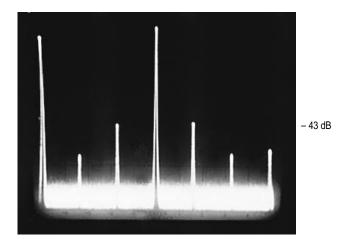


Figure 4. Input to Doubler (Pin 13) (50 MHz x 3 Component)

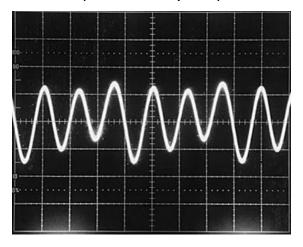


Figure 6. Spectrum

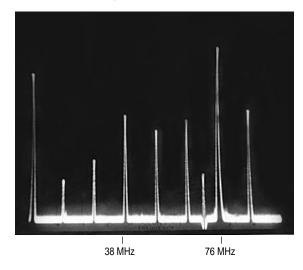


Figure 8. Modulation Spectrum (1.0 kHz Showing Carrier Null)

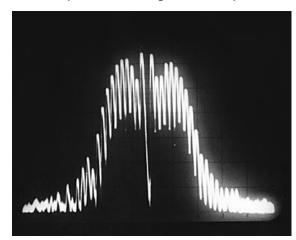


Figure 9. 144 MHz/x12 Multiplier

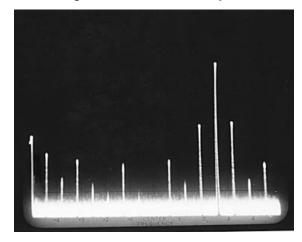


Figure 10. Circuit Side View

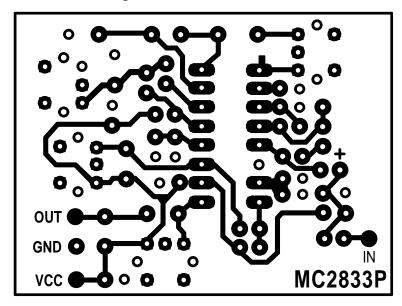


Figure 11. Ground Plane on Component Side

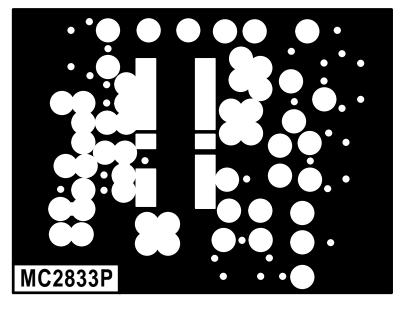
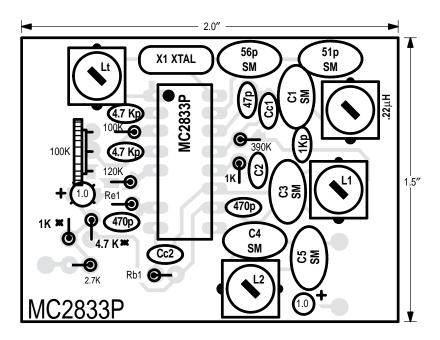


Figure 12. Component View



- NOTES: Positive artwork provided.

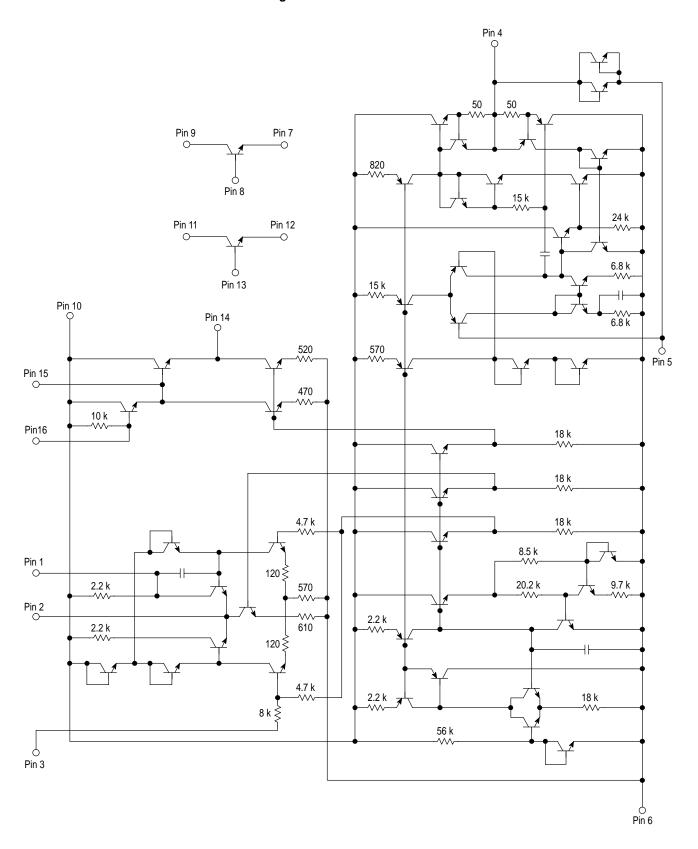
  Drill holes must be plated to ensure making all ground (VEE) connections!

  Resistors labelled \* are used for biasing of electret microphone if used.

  Capacitors labelled "SM" are silver mica.

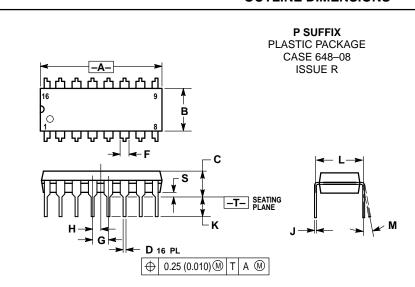
  - Final board size 1.5" × 2.0".

Figure 13. Circuit Schematic



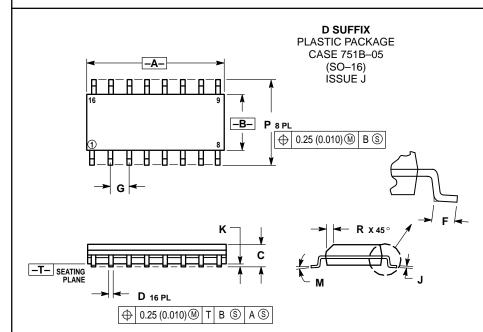
#### MC2833

#### **OUTLINE DIMENSIONS**



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
- DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- DIMENSION B DOES NOT INCLUDE MOLD FLASH.
- ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
C	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27	BSC	
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
М	0°	10 °	0°	10 °	
S	0.020	0.040	0.51	1.01	



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050	BSC
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

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